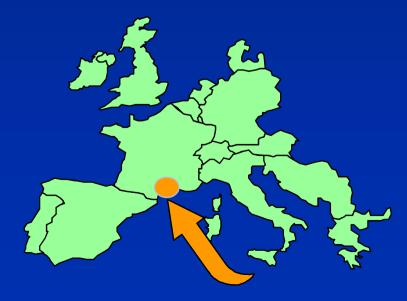
60th IFIP WG 10.4 Meeting



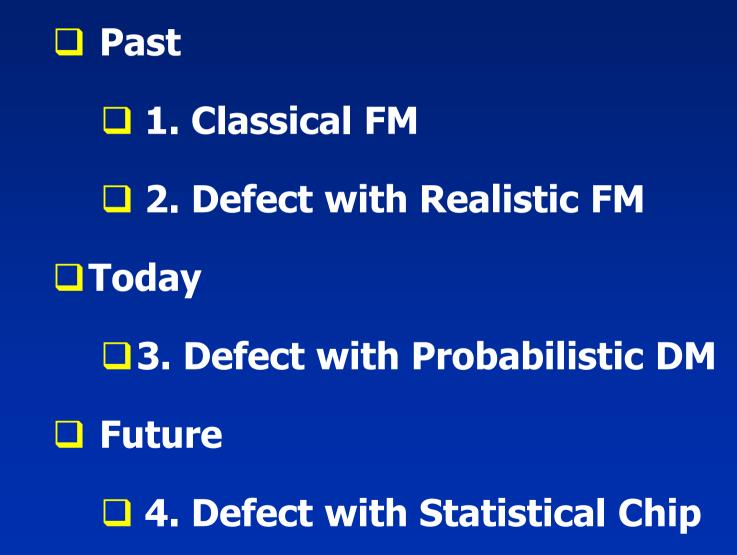
Testing for Realistic Defects in CMOS Technology: From a Deterministic to a Statistical View

M. Renovell

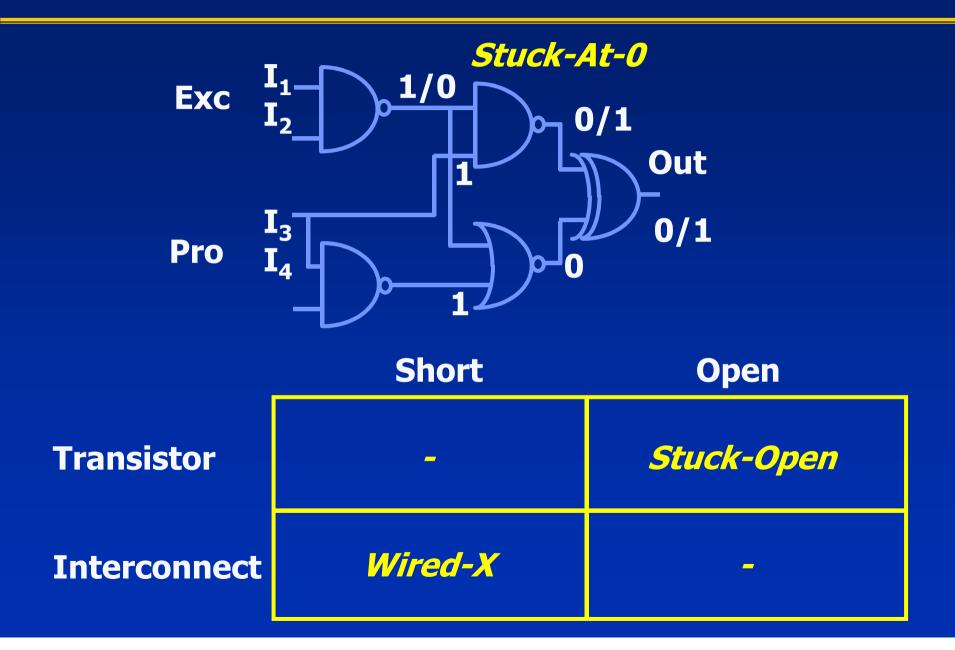
LIRMM - CNRS / University of Montpellier - FRANCE

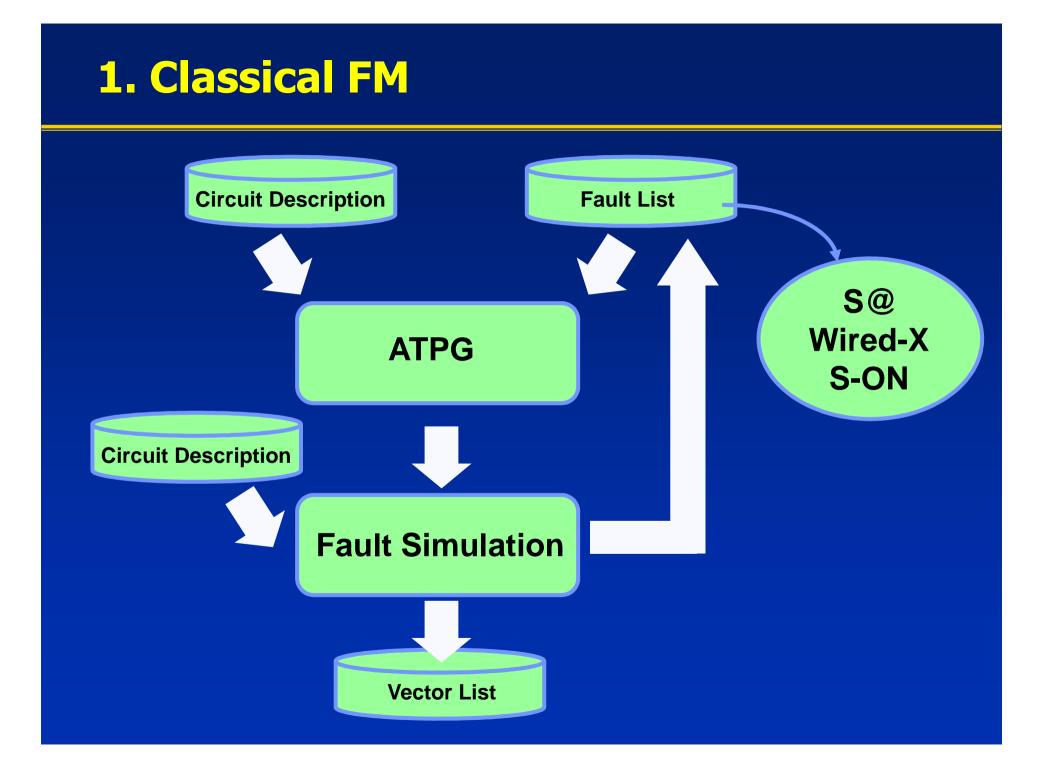


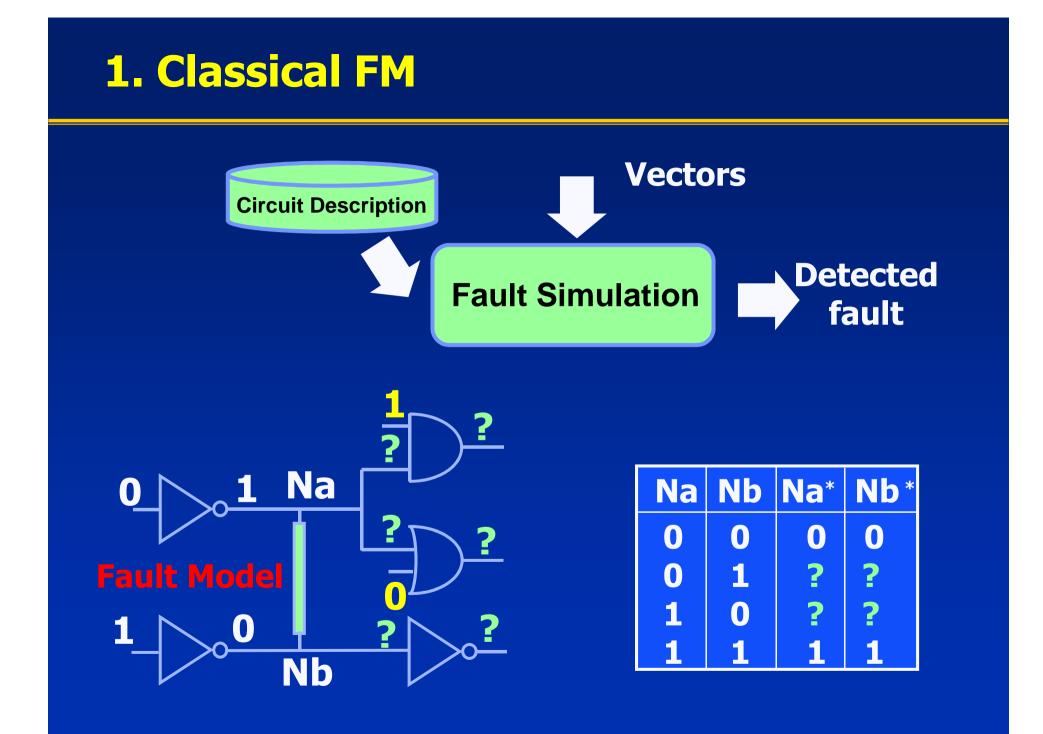




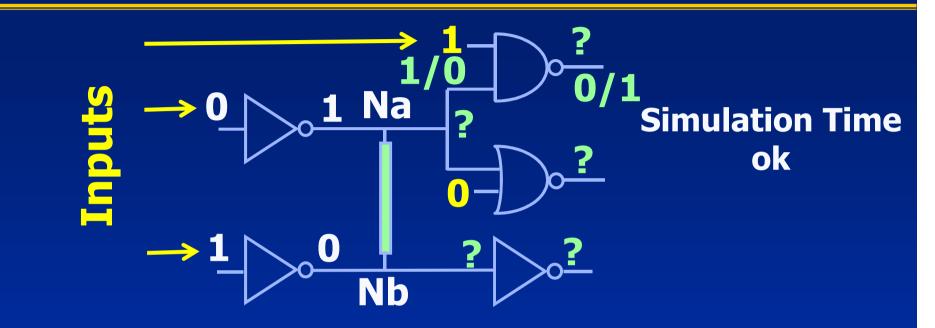
1. Classical FM











Wired-And

Na	Nb	Na.Nb
0	0	0
0	1	0
1	0	0
1	1	1



Na

Na Nb

Wired-Or

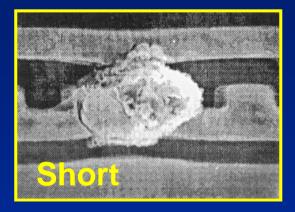
Na	Nb	Na+Nb
0	0	0
0	1	1
1	0	1
1	1	1



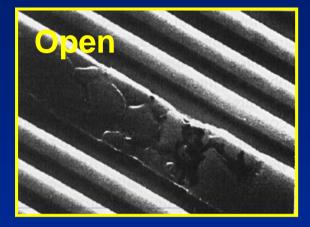
Classical Fault Model

Controlled

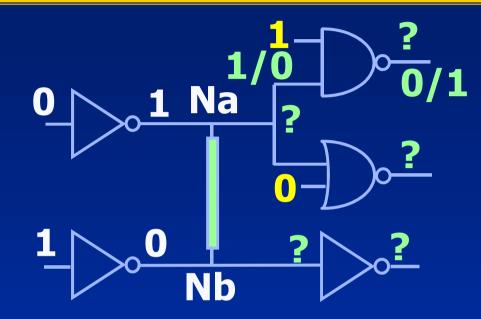




Defects

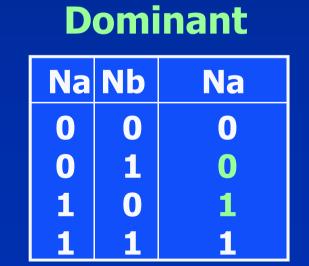


	Short	Open
Transistor	Gate-Oxide-Short	Floating Gate
Interconnect	Short	<i>Open</i>



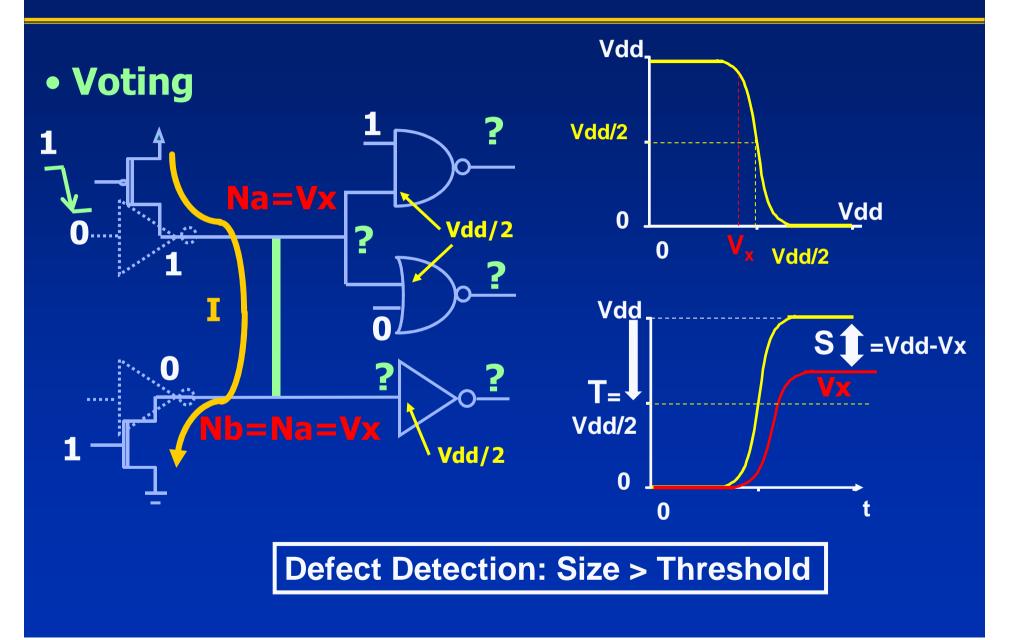
Wired-And

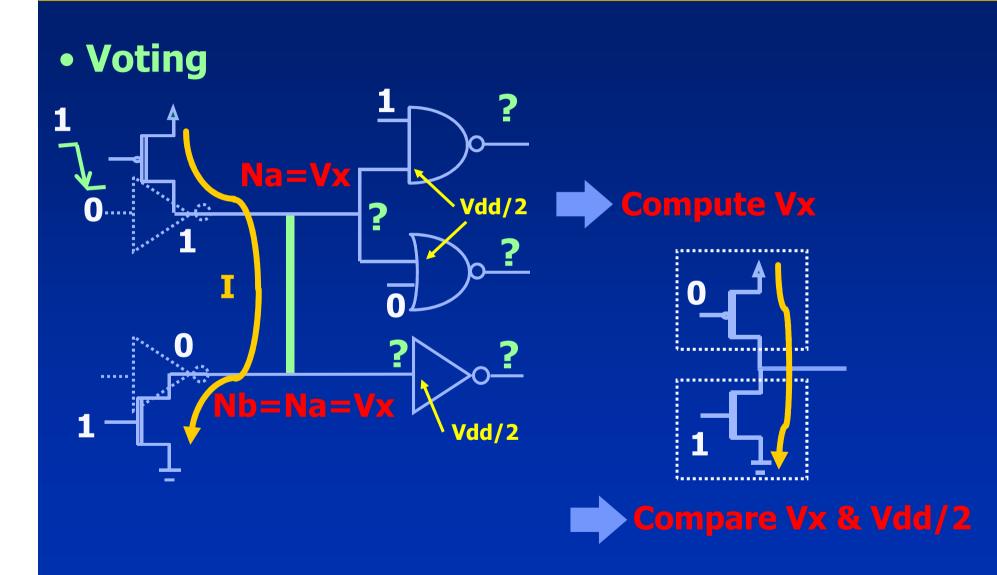
Na	Nb	Na.Nb
0	0	0
0	1	0
1	0	0
1	1	1

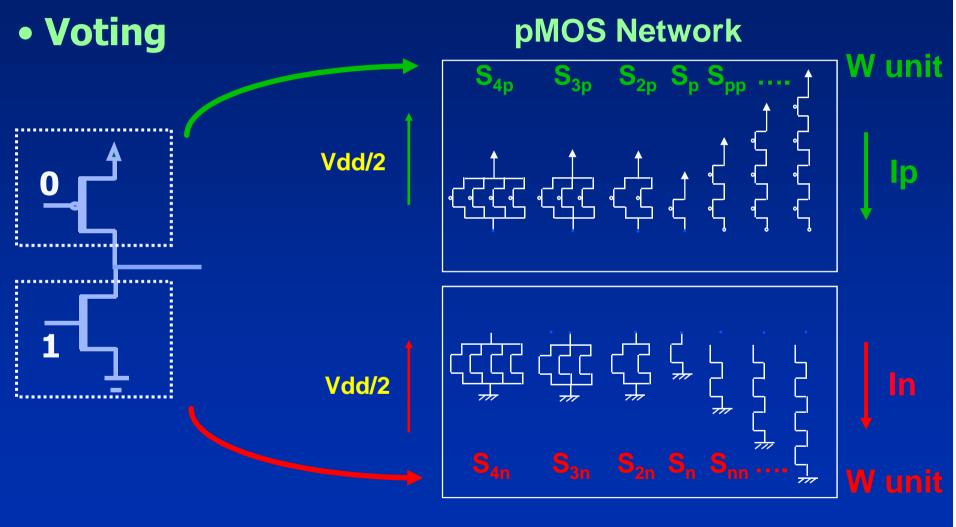


Na	Nb	Na+Nb
0	0	0
0	1	1
1	0	1
1	1	1

Wired-Or

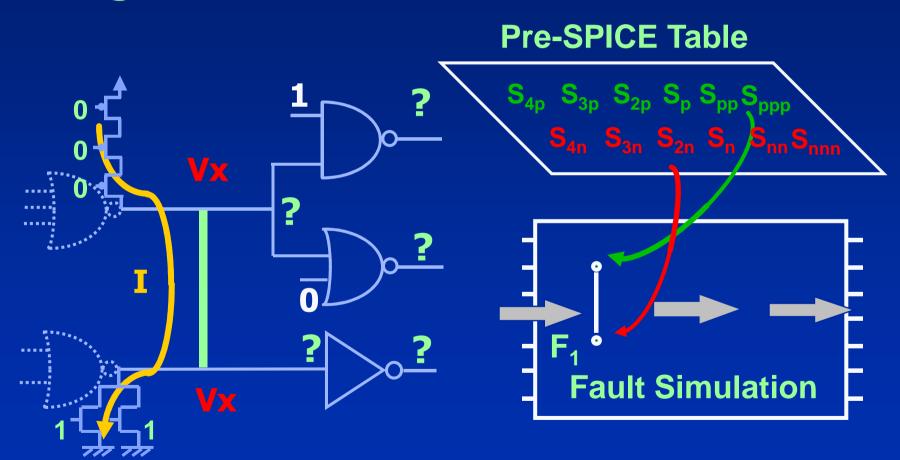


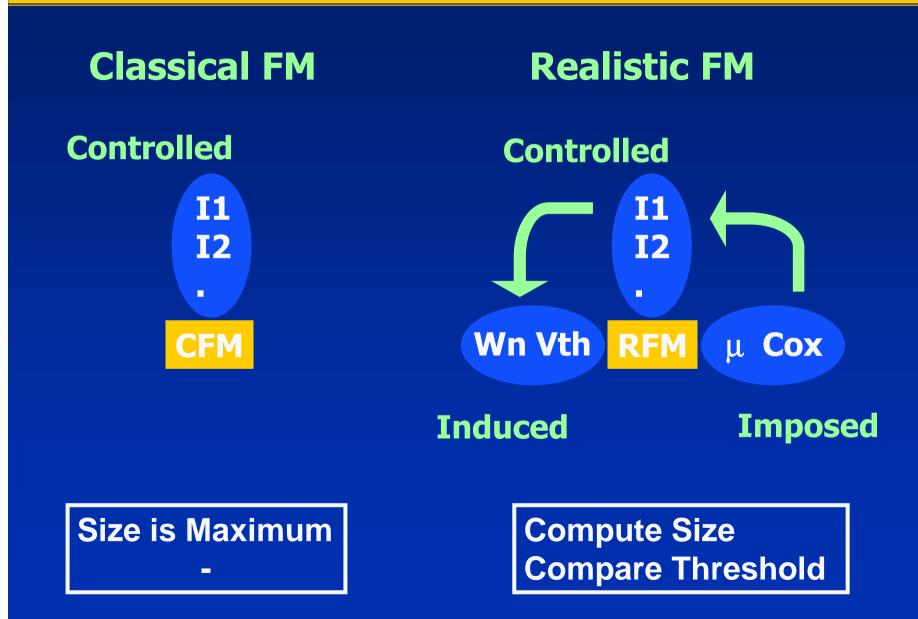


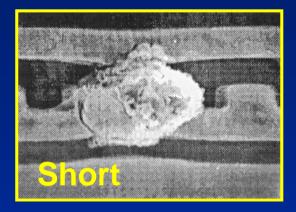


nMOS Network

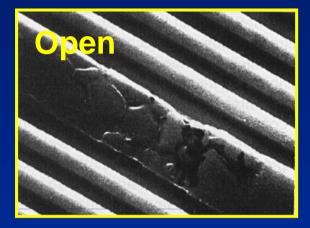
Voting



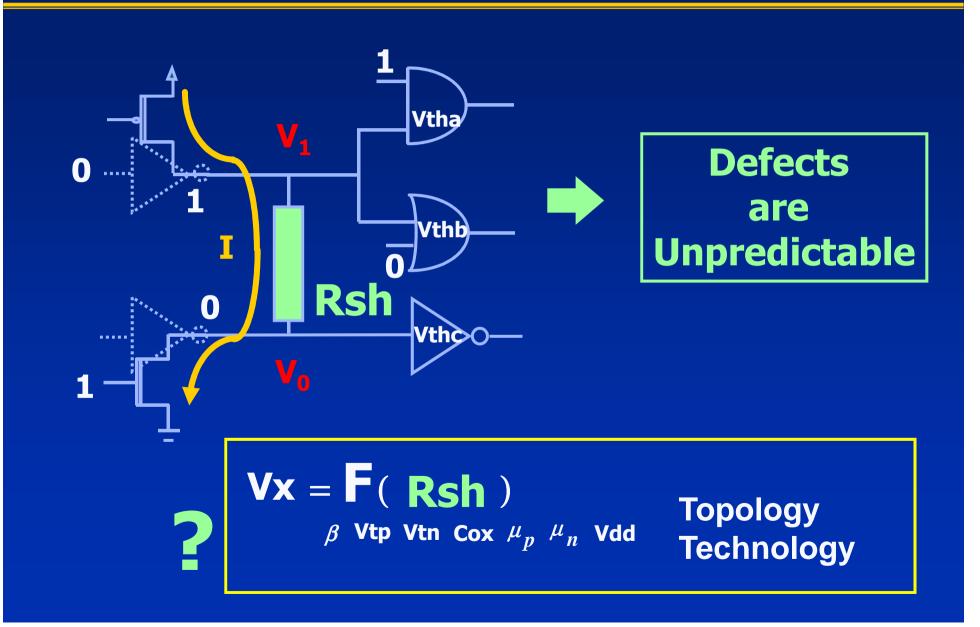


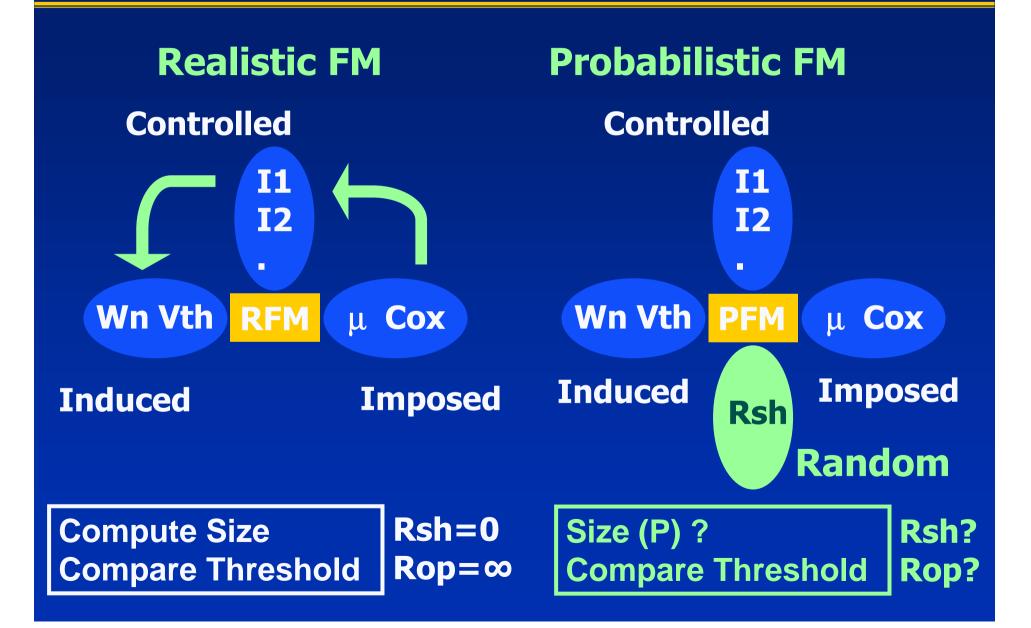


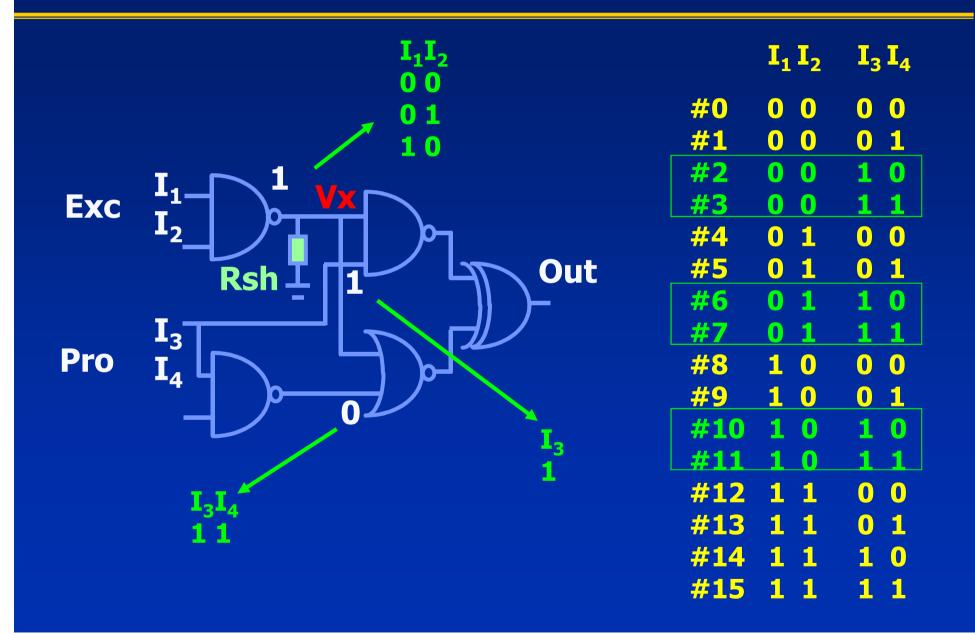
Defects

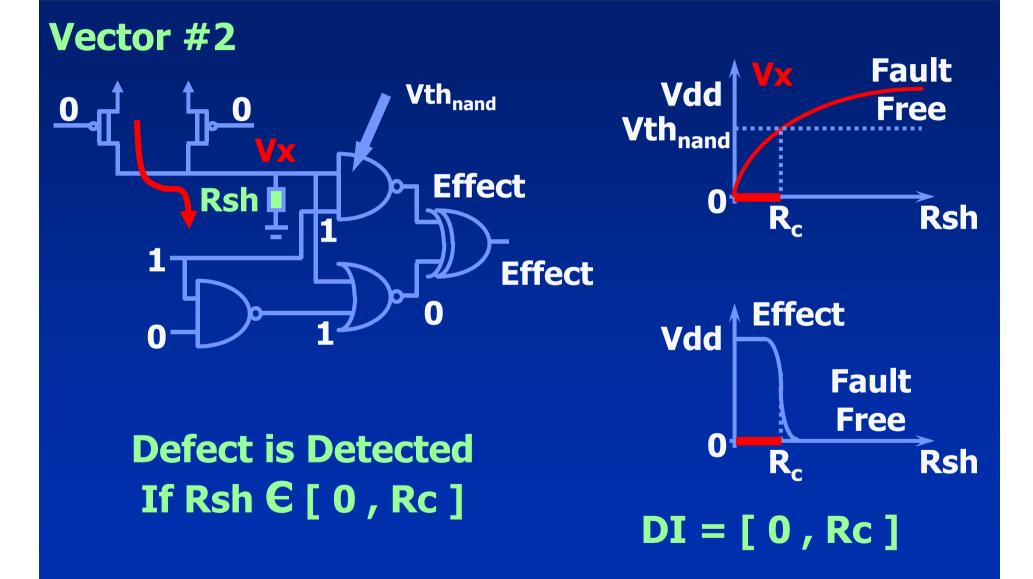


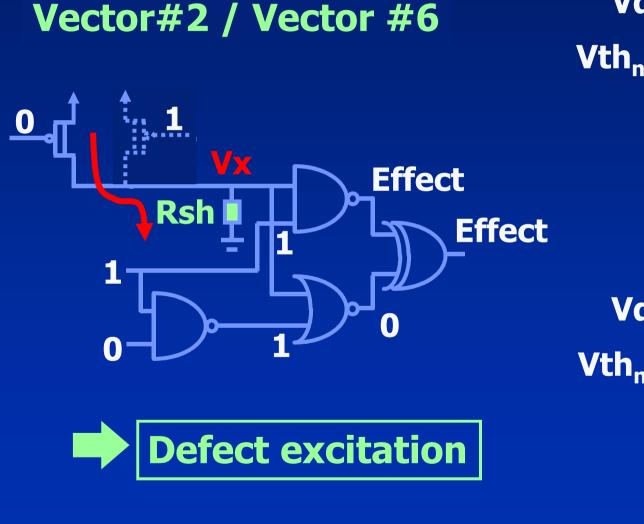
	Short	Open
Transistor	Gate-Oxide-Short	Floating Gate
Interconnect	Resistive Short	Resistive Open

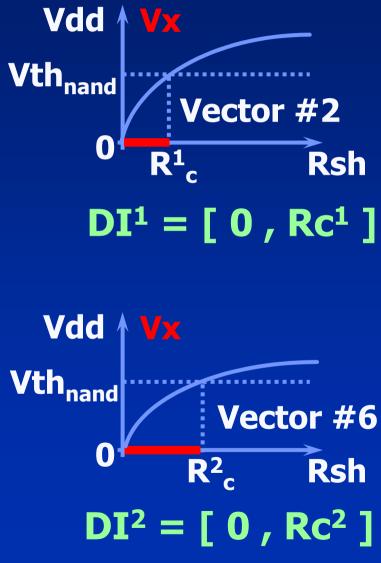


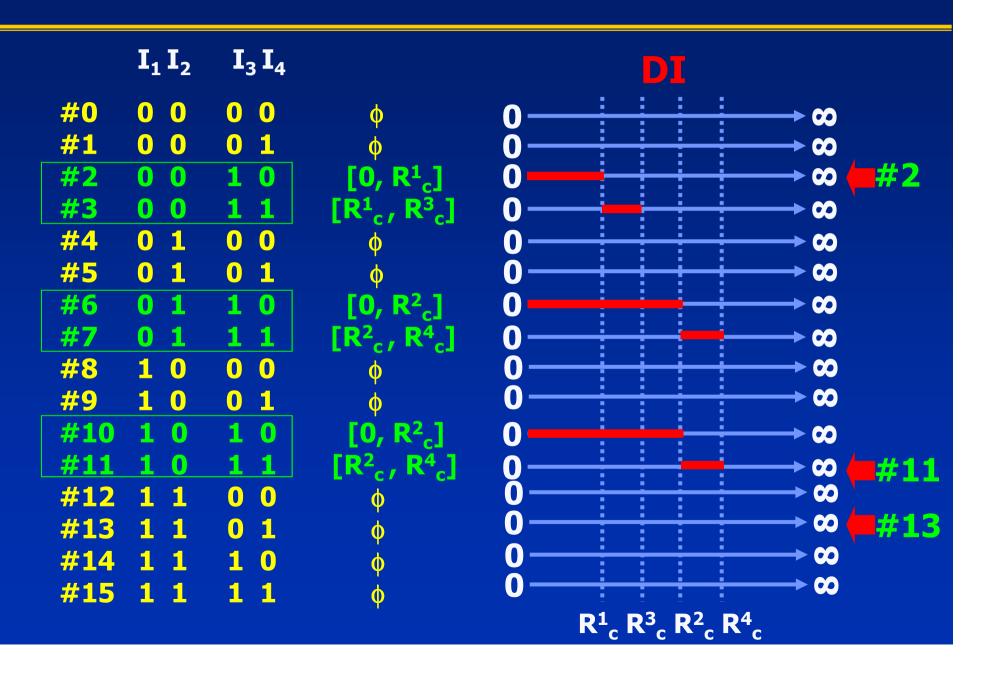


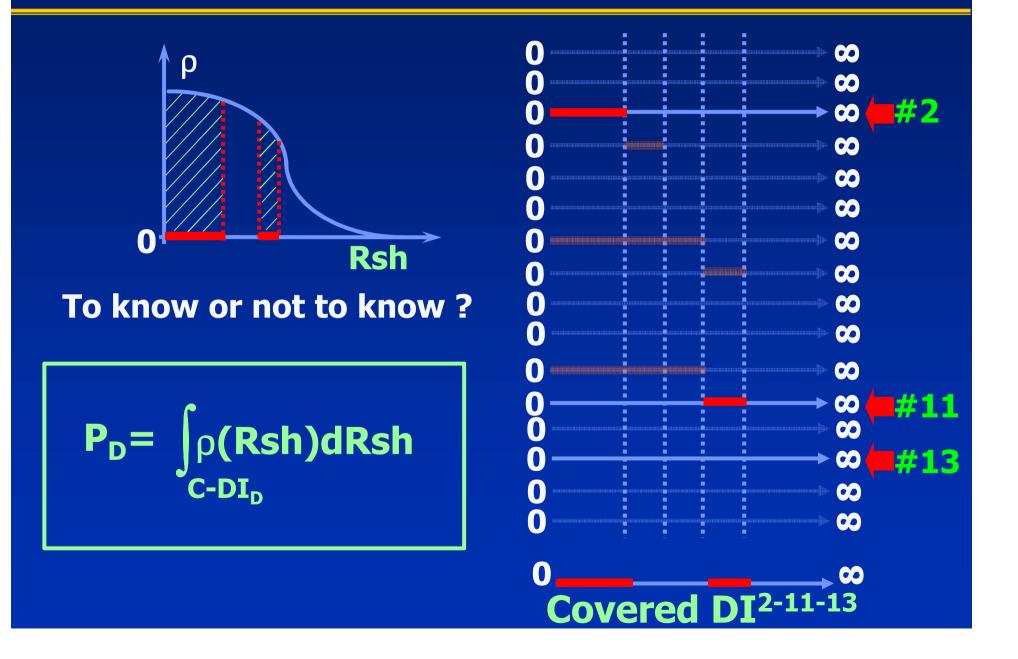


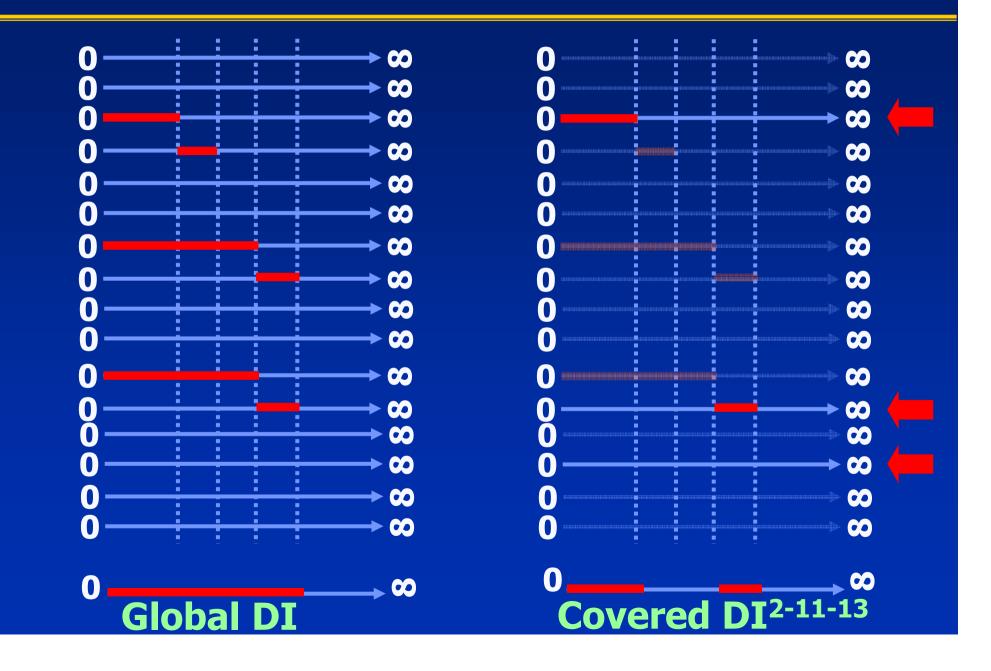




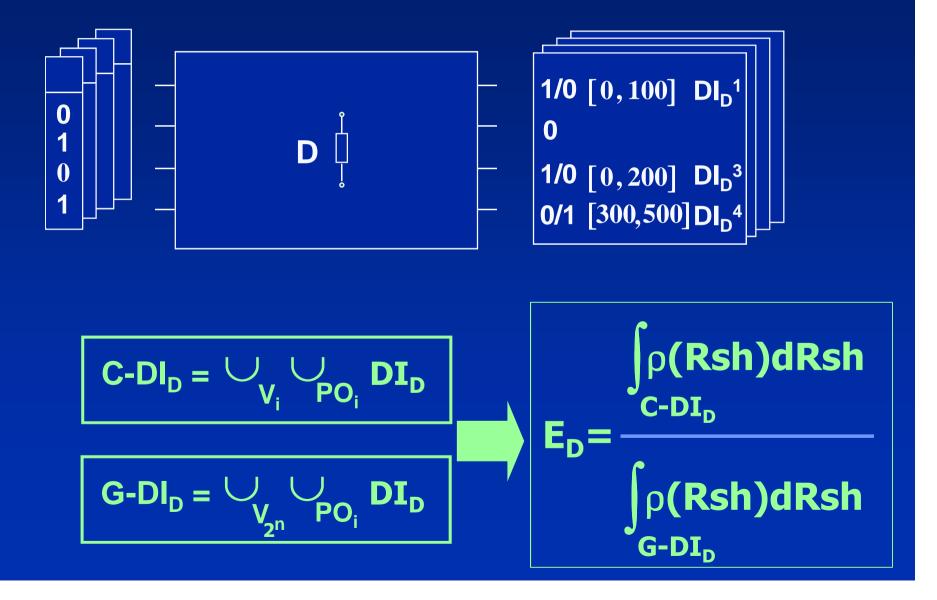




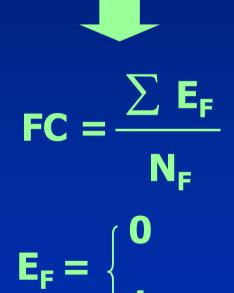




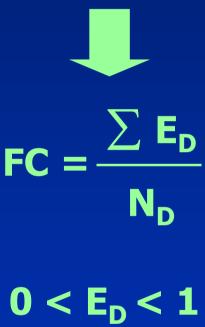
3. Defect with Probabilistic FM 1 3 2 **Global DI** 0 Rsh Covered DI²⁻¹¹⁻¹³ $\mathbf{0}$ Rsh ρ**(Rsh)dRsh** C-DI_D **E**_D ρ**(Rsh)dRsh** G-DI



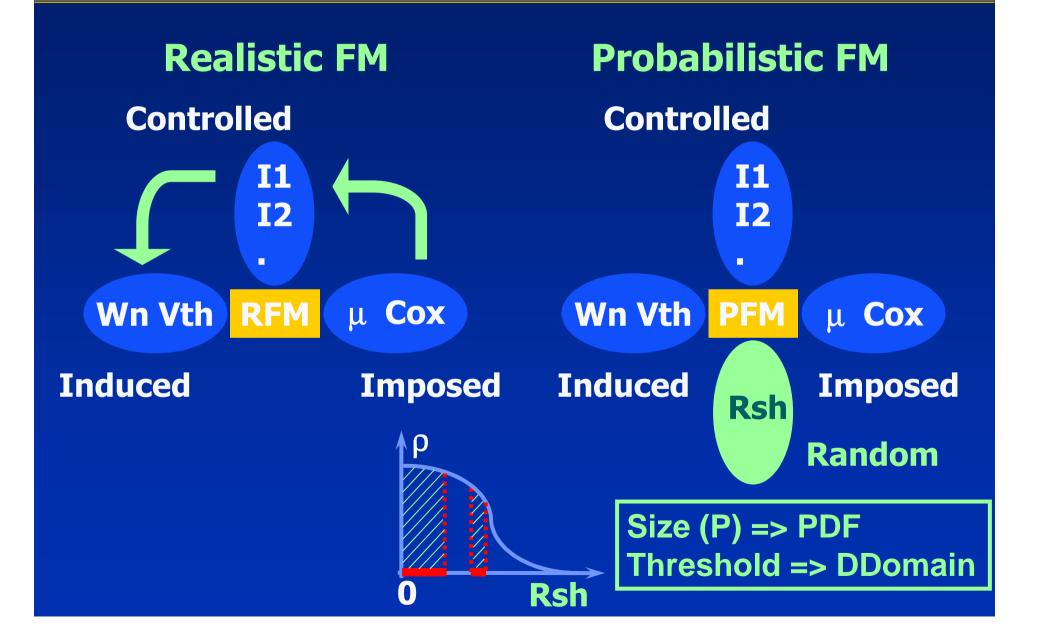
Classical FM Realistic FM

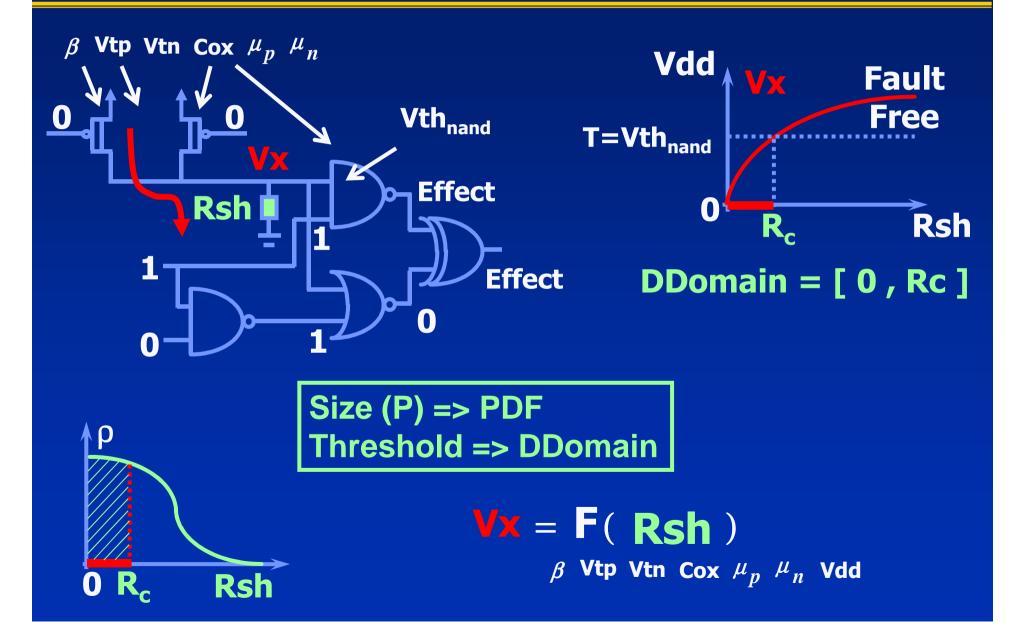


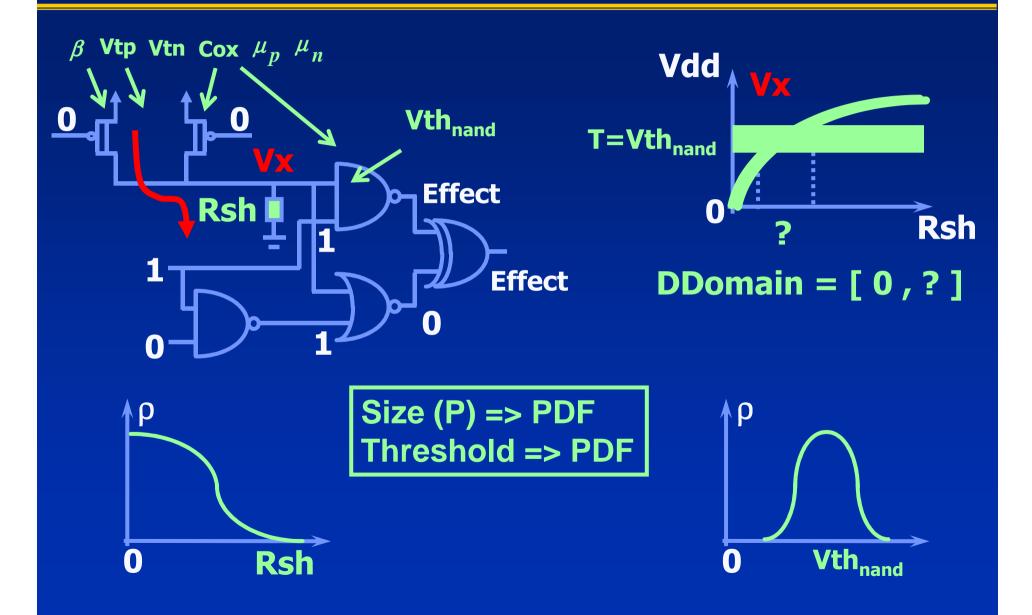
Probabilistic FM

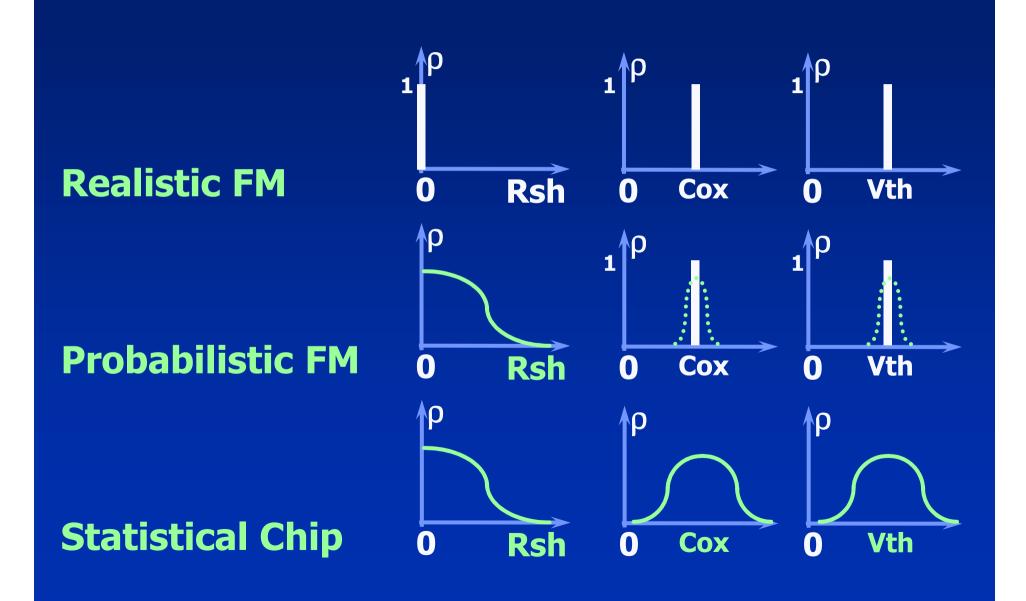


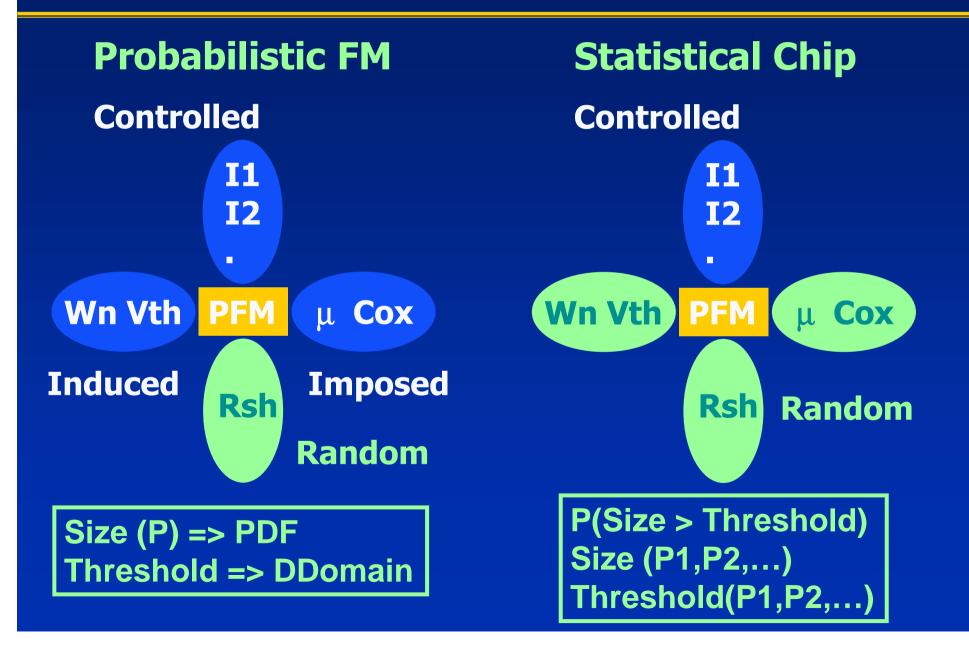
 $< E_D < \int_{C-DI_D} \int_{G-DI_D}$













Past

1. Classical FM → Chip Det / Fault Det
2. Realistic FM → Chip Det / Def Det

□ 3. Probabilistic FM → Chip Det / Def Stat

Future

□ 4. Statistical Chip → Chip Stat / Def Stat